





#### 80V NPN SILICON LOW SATURATION TRANSISTOR IN SOT23

#### **Features**

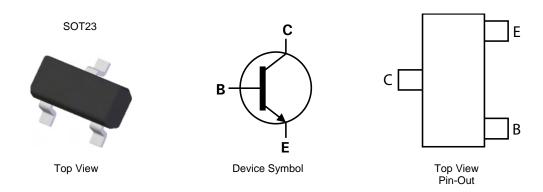
- BV<sub>CEO</sub> > 80V
- I<sub>C</sub> = 1.5A Continuous Collector Current
- $R_{CE(SAT)} = 90 \text{m}\Omega$  for a low equivalent On-Resistance
- 625mW Power dissipation
- h<sub>FF</sub> specified up to 5A for high current gain hold up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

#### **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (approximate)

### **Applications**

- DC-DC Modules
- Power Management Functions
- Motor control and drive functions
- CCFL Backlighting Inverters



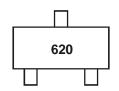
### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT620TA	AEC-Q101	620	7	8	3,000
FMMT620QTA	Automotive	620	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com

### **Marking Information**



620 = Product Type Marking Code





## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	100	V
Collector-Emitter Voltage	$V_{CEO}$	80	V
Emitter-Base Voltage	$V_{EBO}$	7	V
Continuous Collector Current	Ic	1.5	Α
Peak Pulse Current	I <sub>CM</sub>	5	Α
Base Current	lΒ	500	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

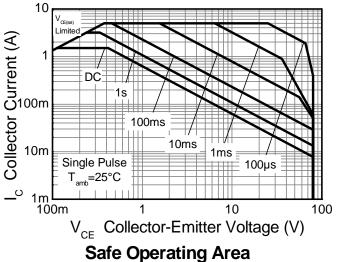
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	625	mW
Power Dissipation (Note 7)	$P_{D}$	806	mW
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	200	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	$R_{\theta JA}$	155	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R <sub>0</sub> JL	194	°C/W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C

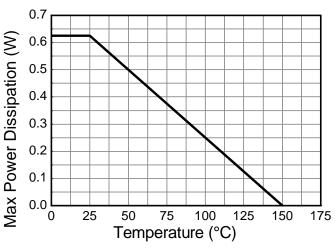
Notes:

<sup>6.</sup> For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
7. Same as note 6, except the device is measured at t ≤ 5 sec.
8. Thermal resistance from junction to solder-point (at the end of the collector lead).

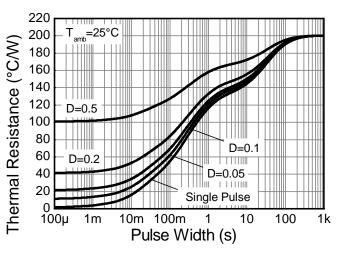


## **Thermal Characteristics and Derating information**

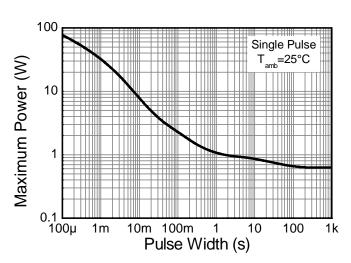








**Derating Curve** 



**Transient Thermal Impedance** 

**Pulse Power Dissipation** 





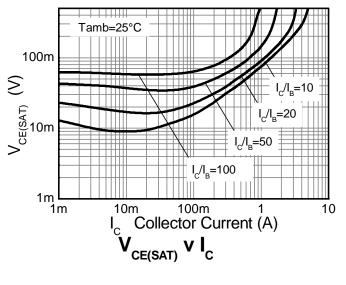
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

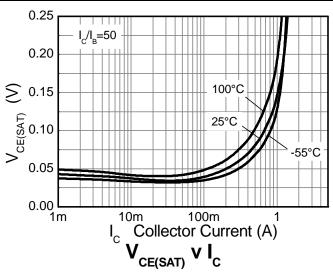
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	180	-	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	80	110	-	V	$I_C = 1mA$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	7	8	-	V	$I_{E} = 100 \mu A$
Collector Cut-off Current	I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> = 80V
Emitter Cut-off Current	I <sub>EBO</sub>	-	-	100	nA	$V_{EB} = 6.0V$
Collector Emitter Cut-off Current	I <sub>CES</sub>	-	-	100	nA	V <sub>CES</sub> = 80V
Static Forward Current Transfer Ratio (Note 9)	hFE	200 300 110 60 20	450 450 170 90 30 10	- 900 - - - -	-	$\begin{split} &I_{C} = 10\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 200\text{mA}, \ V_{CE} = 2\text{V} \\ &I_{C} = 1\text{A}, \ V_{CE} = 2\text{V} \\ &I_{C} = 1.5\text{A}, \ V_{CE} = 2\text{V} \\ &I_{C} = 3\text{A}, \ V_{CE} = 2\text{V} \\ &I_{C} = 5\text{A}, \ V_{CE} = 2\text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	- - -	15 45 145 160	20 60 185 200	mV	$I_C = 0.1A$ , $I_B = 10mA$ $I_C = 0.5A$ , $I_B = 50mA$ $I_C = 1A$ , $I_B = 20mA$ $I_C = 1.5A$ , $I_B = 20mA$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	0.86	1.0	V	$I_C = 1.5A$ , $I_B = 50mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(on)}$	-	0.82	0.95	V	$I_C = 1.5A, V_{CE} = 2V$
Transition Frequency	f <sub>T</sub>	100	160	-	MHz	$I_C = 50 \text{mA}, V_{CE} = 10 \text{V},$ f = 100MHz
Collector Output Capacitance	$C_obo$	-	11.5	18	pF	$V_{CB} = 10V$ , $f = 1MHz$
Turn-On Time	t <sub>(on)</sub>	-	86	-	ns	$V_{CC} = 10V, I_C = 500mA,$
Turn-Off Time	t <sub>(off)</sub>	-	1128	-	ns	$I_{B1} = -I_{B2} = 25 \text{mA}$

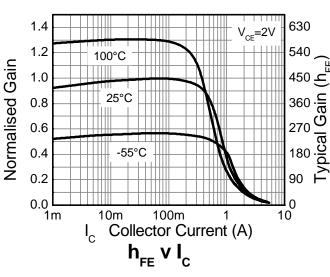
Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%

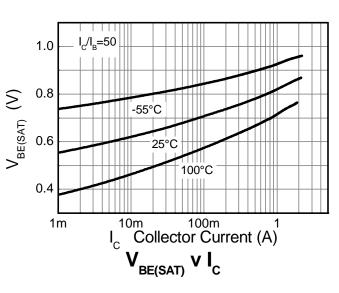


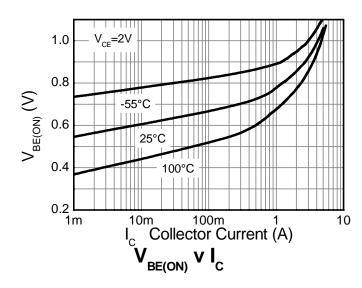
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)









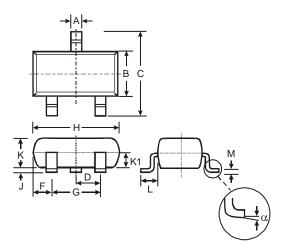






## **Package Outline Dimensions**

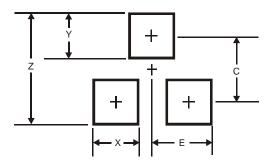
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
C	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	1	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
С	2.0
Е	1.35





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